NSN 5961-01-016-8489

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View Online at https://aerobasegroup.com/nsn/5961-01-016-8489
Inclosure Material:
Ceramic
Overall Length:
1.630 inches
Overall Diameter:
0.565 inches
Mounting Method:
Compression
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
600.0 repetitive peak off-state voltage and 600.0 repetitive peak reverse voltage
Current Rating Per Characteristic:
3500.00 amperes peak forward surge current absolute
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Terminal Type And Quantity:
1 tab, solder lug and 1 pin and 1 case
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0